



50G InGaAs Photodiode RF ROSA Package

Description

50G InGaAs photodiode built-in a RF TO-Can package. This delivers flat performance with broad temperature operating range. Utilizing our proprietary edge mounted TO-can package this ruggedized design offers great RF performance in a TO-package. Low parasitic RF design shows negligible ringing in pulse response. The mechanical clamp allows the use of PCB thickness ranging from 0.1-1.6mm. RF pin does not need to be soldered to PCB, this allows for easy mounting and replacement. The device body is Kovar (4J29) with AU finish.

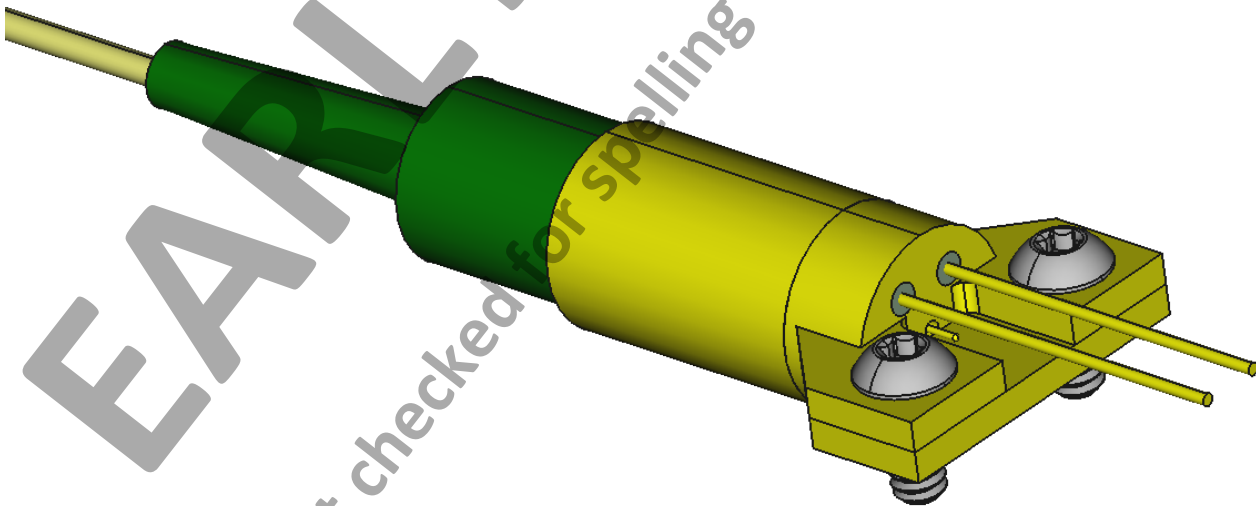
Features

- RF TO-Can Package
- Single mode Pigtail cable
- Low Dark current
- High Bandwidth
- Flat response
- High Linearity
- Easily mounted and removed



Applications

- 5G/6G
- Datacenters
- RF over Fiber (RFoF)



Electro-Optical Characteristics ($T_{op} 23 \pm 3^{\circ}C$, unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Response Spectrum	λ	1100		1650	nm	
Dark Current	I_d		0.25	4.0	nA	$V_r = 5.0 V$
Reverse Breakdown Voltage	V_{BR}	20			V	$I = 10 \mu A$
Responsivity	R_e	0.6			A/W	$\lambda = 1310 P_{in} 0.5 mW V = 1.0v$
Bandwidth	BW		50		GHz	$\lambda = 1550 P_{in} 0.5 mW V = 2.5v$ $R_L = 50\Omega$ at -3 dB
Capacitance	C_p		40		fF	$F = 1 MHz V = 4.0 v$
Saturation power	P			10	dBm	$V_r = 5V$

Absolute Maximum Ratings

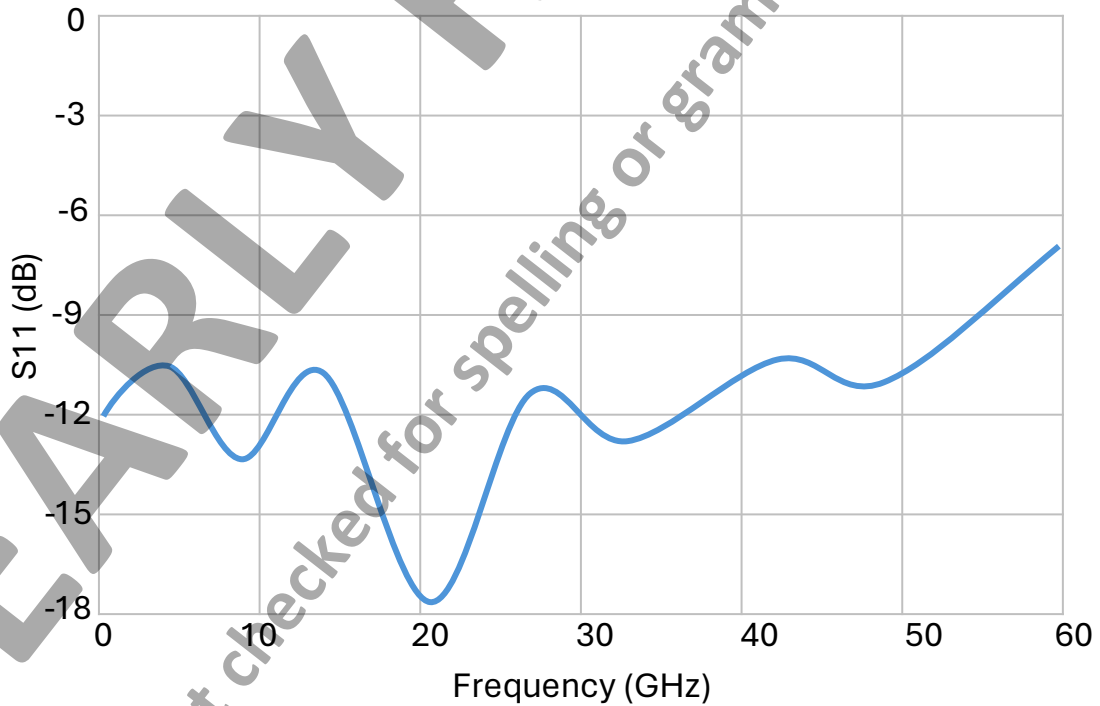
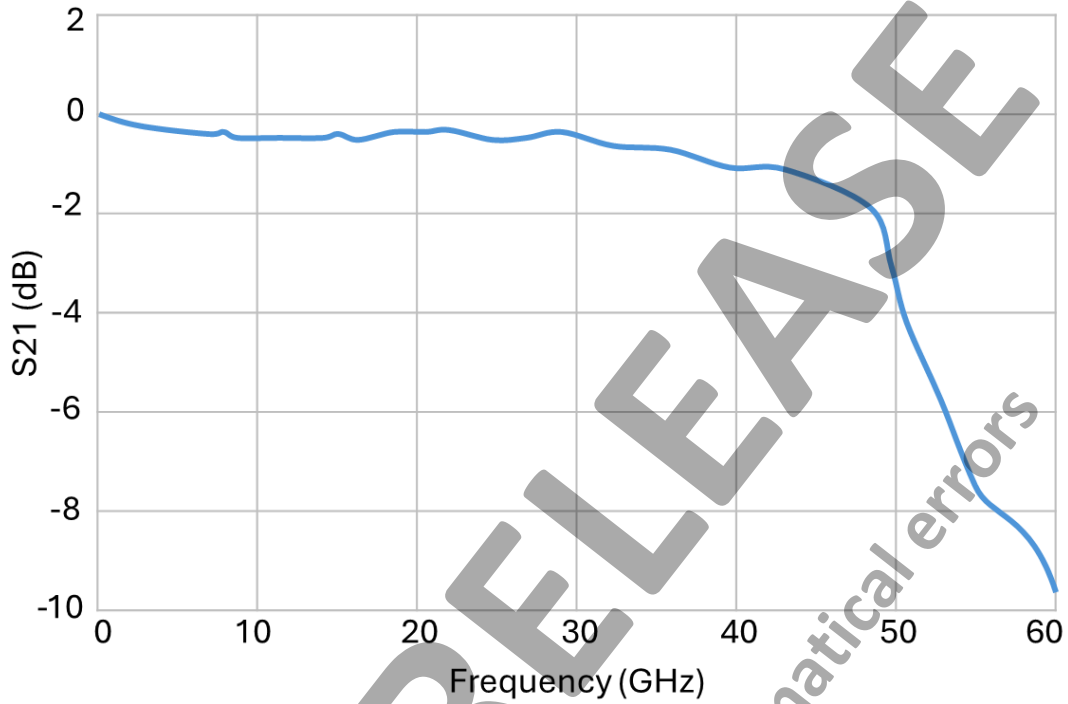
Parameter	Symbol	Condition	Min.	Max.	Unit
Reverse Voltage	V_r			10	V
Forward Current	I_F			10	mA
Reverse Current	I_R			5	mA
Optical Input power	P_{in}			10	mW
Storage Temperature	T_{stg}		-25	90	$^{\circ}C$
Storage Humidity	H_{stg}			85	% r.H.
Operating Temperature	T_{op}		-10	80	$^{\circ}C$
Soldering Temperature	T_{st}	60 sec		200	$^{\circ}C$
ESD Susceptibility		HBM		200	V

Operating at maximum operating specs for prolong periods of time will damage the device.

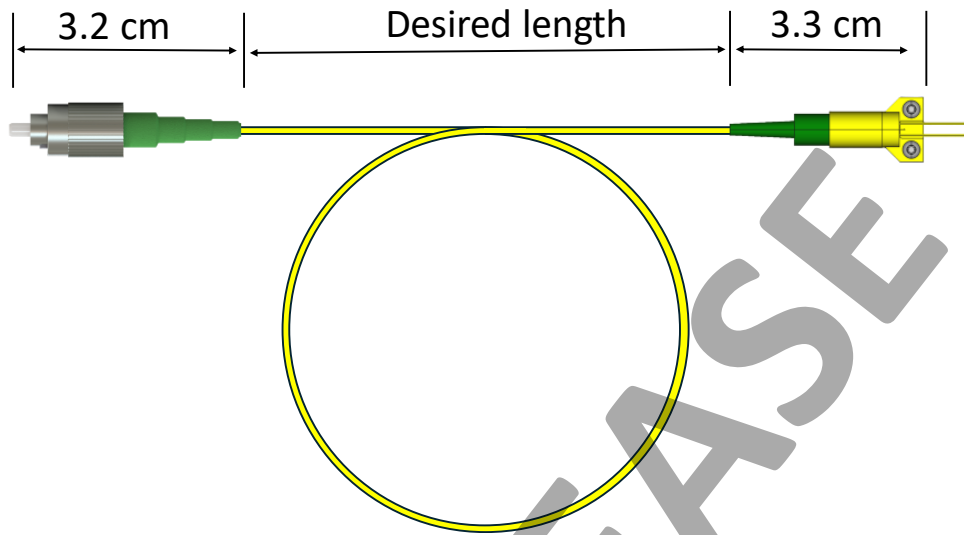


Typical Performance Curves (Top 23°C, 801 PTs, 16 AVGs, 1.5% smoothing)

RF performance dependent on PCB design and optimization. Data shown for Rogers® RO3003 with Ground-backed Co-planar waveguide (GB-CPW). The GB-CPW was de-embedded.

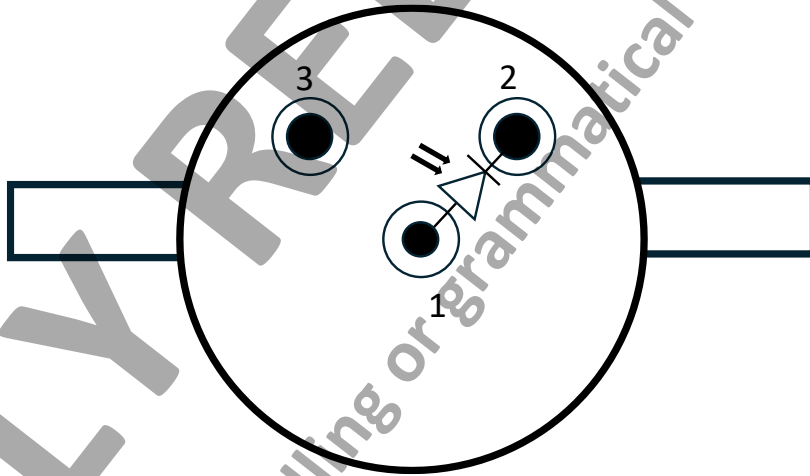


Device Dimensions



Connector length for FC/APC Connector

Device Pin Configuration (Internal View)



Pin Number	Function
1	RF Out/PD Anode (+)
2	PD Cathode (-)
3	Ground

Table 1: Device Pin out



Device Nomenclature

P50-FTO-XX

Product Line – 50G Photodiode

Device body style – RF TO-CAN

Optical Connector

(FA) FC/APC

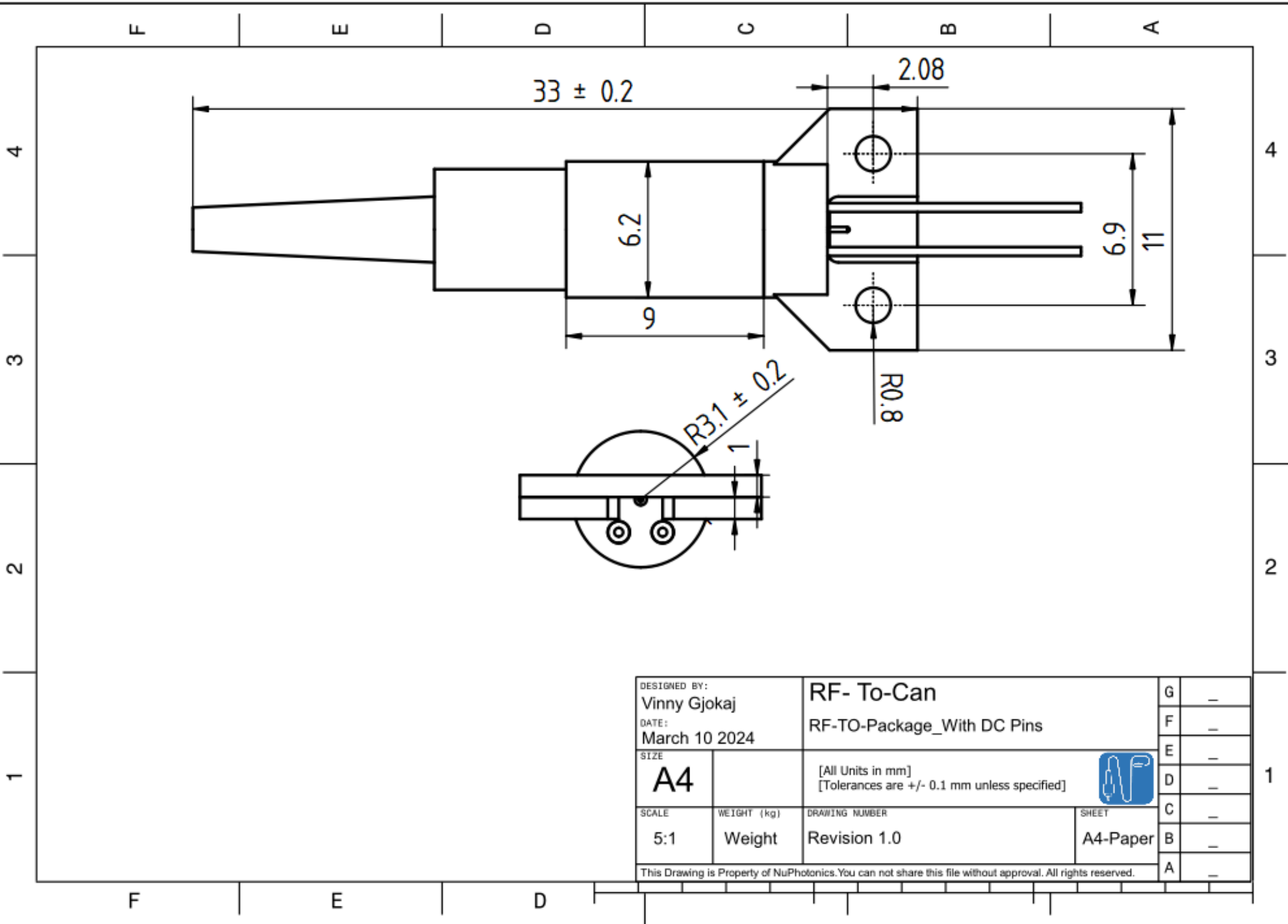
(FP) FC/PC


(SA) SA/APC

(SP) SC/PC

EARLY RELEASE
Not checked for spelling or grammatical errors





DESIGNED BY: Vinny Gjokaj		RF- To-Can		G	-
DATE: March 10 2024		RF-TO-Package_With DC Pins		F	-
SIZE A4		[All Units in mm] [Tolerances are +/- 0.1 mm unless specified]		E	-
SCALE 5:1	WEIGHT (kg) Weight	DRAWING NUMBER Revision 1.0	SHEET A4-Paper	D	-
This Drawing is Property of NuPhotonics. You can not share this file without approval. All rights reserved.				C	-
				B	-
				A	-

Inquiry Information

Sales: All inquiries regarding sales please contact Sales@NuPhotonics.com

General: If you are interested in a custom solution, general information, or engineering related information please contact Inquiry@NuPhotonics.com

EARLY RELEASE
Not checked for spelling or grammatical errors

IMPORTANT NOTICES AND DISCLAIMERS

Warranty: NUPHOTONICS PROVIDES ALL OF THE INFORMATION ON TECHNICAL AND RELIABILITY DATA. THIS INCLUDES INFORMATION PRESENTED IN DATA SHEETS, DESIGN FILES, APPLICATIONS, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD-PARTY INTELLECTUAL PROPERTY RIGHTS.

The information and resources are presented and intended for developers that are skilled and adequately qualified to work with this technology. You, the customer, are solely responsible for and accept full responsibility for selecting the appropriate NuPhotonics devices for your application. You accept the sole responsibility of designing, validating, and testing your application. You bear all responsibility for your application meeting standards, safety, security, and other regulatory requirements.

NuPhotonics retains the right to change these resources without notice. All rights are reserved for NuPhotonics. NuPhotonics grants you permission to use the information in these resources to design with NuPhotonics devices. Reproduction and display of these resources is prohibited. No Third-party licenses are offered. You will fully indemnify NuPhotonics against any claims, damages, costs, losses, and liabilities that arise from you using these resources.

NuPhotonics does not accept and objects to any terms you have proposed.

For terms and conditions for all NuPhotonics products please refer to www.nuphotonics.com Legal section.

Definitions: Product State

Alpha Build: Devices in Alpha build are in internal engineering build and testing stages. Major changes may happen for production build.

Beta Build: Devices in Beta build are for external customer and engineering sample testing stages. Minor changes may happen for production build.

Production Build: Customer ready devices. Small appearance changes may occur between devices.

Obsolete: Currently not supported.